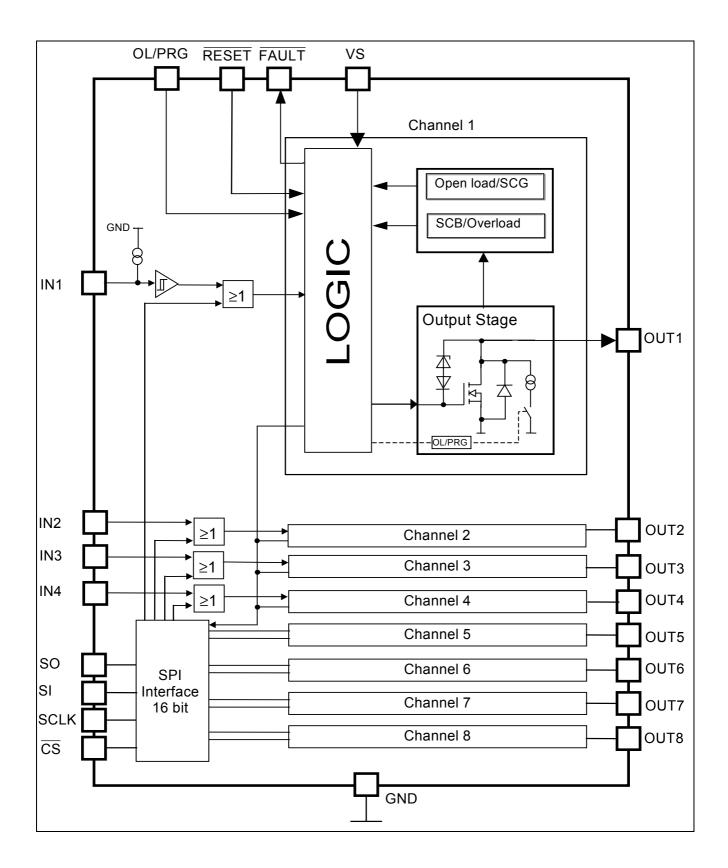


# **Detailed Block Diagram**





# Pin Description

	Pin Configuration (Top view)							
Pin	Symbol	Function						
1	GND	Ground						
2	NC	not connected						
3	OUT1	Power Output Channel 1						
4	OUT2	Power Output Channel 2						
5	IN1	Input Channel 1						
6	IN2	Input Channel 2						
7	VS	Supply Voltage						
8	OL/PRG	Open load actice/inactive Program Pin						
9	IN3	Input Channel 3						
10	IN4	Input Channel 4						
11	OUT3	Power Output Channel 3						
12	OUT4	Power Output Channel 4						
13	NC	not connected						
14	GND	Ground						
15	GND	Ground						
16	NC	not connected						
17	OUT5	Power Output Channel 5						
18	OUT6	Power Output Channel 6						
19	CS	Chip Select						
20	FAULT	General Fault Flag						
21	SO	Serial Data Output						
22	SCLK	Serial Clock						
23	SI	Serial Data Input						
24	RESET	Reset						
25	OUT7	Power Output Channel 7						
26	OUT8	Power Output Channel 8						
27	NC	not connected						
28	GND	Ground						

-		_	
GND	1●	28	GND
NC	2	27	NC
OUT1	3	26	OUT8
OUT2	4	25	OUT7
IN1	5	24	RESET
IN2	6	23	SI
VS	7	22	SCLK
OL/PRG	8	21	SO
IN3	9	20	FAULT
IN4	10	19	CS
OUT3	11	18	OUT6
OUT4	12	17	OUT5
NC	13	16	NC
GND	14	15	GND

P-DSO 28



# Maximum Ratings for $T_j = -40^{\circ}$ C to 150°C

Parameter	Symbol	Values	Unit
Supply Voltage	Vs	-0.3 +7	V
Continuous Drain Source Voltage (OUT1OUT8)	V <sub>DS</sub>	45	V
Input Voltage, All Inputs and Data Lines	V <sub>IN</sub>	- 0.3 + 7	V
Operating Temperature Range	Tj	- 40 + 150	°C
Storage Temperature Range	$T_{\rm stg}$	- 55 + 150	
Output Current per Channel (see el. characteristics)	I <sub>D(lim)</sub>	I <sub>D(lim) min</sub>	А
Output Current per Channel @ $T_A = 25^{\circ}C$	I <sub>D</sub>	250	mA
(All 8 Channels ON; Mounted on PCB ) <sup>1)</sup>			
Output Clamping Energy	E <sub>AS</sub>	10	mJ
/ <sub>D</sub> = 0.25 A			
Power Dissipation (mounted on PCB) @ $T_A = 25^{\circ}C$	P <sub>tot</sub>	2	W
Electrostatic Discharge Voltage (Human Body Model)	V <sub>ESD</sub>	2000	V
according to MIL STD 883D, method 3015.7 and EOS/ESD assn. standard S5.1 - 1993			
DIN Humidity Category, DIN 40 040		E	
IEC Climatic Category, DIN IEC 68-1		40/150/56	
Thermal Resistance			
junction - pin	$R_{ m thJP}$	25	K/W
junction - ambient @ min. footprint	$R_{ m thJA}$	80	

<sup>&</sup>lt;sup>1)</sup> Output current rating so long as maximum junction temperature is not exceeded. At  $T_A$  = 125 °C the output current has to be calculated using  $R_{thJA}$  according mounting conditions.



# **Electrical Characteristics**

Parameter and Conditions	Symbol	Values	Unit		
$V_{\rm S}$ = 4.5 to 5.5 V ; $T_{\rm j}$ = - 40 °C to + 150 °C ; Reset = H (unless otherwise specified)		min	typ	max	
1. Power Supply					
Supply Voltage	Vs	4.5		5.5	V
Supply Current	I <sub>S</sub>		1.5	3	mA
Supply Current (in Standby Mode, RESET = L) <sup>1)</sup>	I <sub>S(Stdby)</sub>			50	μA
2. Power Outputs					
ON Resistance $V_{\rm S}$ = 5 V; $I_{\rm D}$ = 500 mA $T_{\rm J}$ = 25°C	R <sub>DS(ON)</sub>		1.7		Ω
$T_{\rm J}$ = 150°C			3	4	
Output Clamping Voltage Output OFF	V <sub>DS(AZ)</sub>	45		60	V
Current Limit	I <sub>D(lim)</sub>	500	750	1000	mA
Output Leakage Current $V_{\text{Reset}} = L^{-2}$	I <sub>D(lkg)</sub>			1	μA
Turn-On Time $I_{\rm D}$ = 0.25 A, resistive load	t <sub>on</sub>		6	10	μs
Turn-Off Time $I_{\rm D}$ = 0.25 A, resistive load	t <sub>OFF</sub>		6	10	μs
3. Digital Inputs		1			
Input Low Voltage	V <sub>INL</sub>	- 0.3		1.0	V
Input High Voltage	V <sub>INH</sub>	2.0			V
Input Voltage Hysteresis	V <sub>INHys</sub>	100	200		mV
Input Pull Down Current (IN1 IN4)	<i>I</i> <sub>IN(14)</sub>	20	50	100	μA
OL/PRG, Reset Pull Up Current	I <sub>IN(OL/PRG,Res)</sub>	20	50	100	μA
Input Pull Down Current (SI, SCLK)	I <sub>IN(SI,SCLK)</sub>	10	20	50	μA
Input Pull Up Current ( $\overline{CS}$ )	I <sub>IN(CS)</sub>	10	20	50	μA
4. Digital Outputs (SO, FAULT)					
SO High State Output Voltage $I_{SOH} = 2 \text{ mA}$	V <sub>SOH</sub>	V <sub>S</sub> – 0.5V			V
SO Low State Output Voltage $I_{SOL} = 2 \text{ mA}$	V <sub>SOL</sub>			0.4	V
SO Output Tri-state Leakage Current $\overline{CS}$ =H, 0 $\leq V_{SO} \leq V_{S}$	I <sub>SOlkg</sub>	-10	0	10	μA
FAULT Output Low Voltage $I_{FAULT} = 1.6 \text{ mA}$	V <sub>FAULTL</sub>			0.4	V
5. Diagnostic Functions					
Open Load Detection Voltage	V <sub>DS(OL)</sub>	0.6*V <sub>S</sub>	0.7*V <sub>S</sub>	0.8*V <sub>S</sub>	V
Output Pull Down Current	I <sub>PD(OL)</sub>	200	300	450	μA
Fault Delay Time	t <sub>d(fault)</sub>	50	100	200	μs
Overload Threshold Current	<i>I</i> <sub>D(lim) 18</sub>	500	700	1000	mA
Overtemperature Shutdown Threshold	$T_{\rm th(sd)}$	170		200	°C
Hysteresis	T <sub>hys</sub>		10		κ

<sup>&</sup>lt;sup>1</sup> Test conditions : No floating digital Inputs <sup>2</sup> Measured on wafer level

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# **Electrical Characteristics cont.**

Parameter and Conditions	Symbol	Values			Unit
$V_{\rm S}$ = 4.5 to 5.5 V ; $T_{\rm j}$ = - 40 °C to + 150 °C ; Reset = H (unless otherwise specified)		min	typ	max	

### 6. SPI-Timing

-						
Serial Clock Frequency	<b>f</b> <sub>SCK</sub>	DC		5	MHz	
Serial Clock Period (1/fclk)	t <sub>p(SCK)</sub>	200			ns	
Serial Clock High Time		<b>t</b> <sub>scкн</sub>	80			ns
Serial Clock Low Time		<b>t</b> <sub>SCKL</sub>	80			ns
Enable Lead Time (falling edge of $\overline{cs}$ to ris CLK)	<b>t</b> <sub>lead</sub>	250			ns	
Enable Lag Time (falling edge of CLK to ris	ing edge of $\overline{cs}$ )	<b>t</b> <sub>lag</sub>	250			ns
Data Setup Time (required time SI to falling	of CLK)	t <sub>su</sub>		25		ns
Data Hold Time (falling edge of CLK to SI)		t <sub>H</sub>		25		ns
Enable Time		<i>t</i> <sub>EN</sub>	250			ns
Disable Time		t <sub>DIS</sub>	250			ns
Data Valid Time	C <sub>L</sub> = 50 pF <sup>1</sup>	<i>t</i> <sub>valid</sub>		110	160	ns
	$C_{L} = 100 \text{ pF}^{1}$			120	170	
	$C_{L} = 220 \text{ pF}^{1}$			150	200	

<sup>&</sup>lt;sup>1</sup> This parameter will not be tested but guaranteed by design



# **Functional Description**

The TLE 6236 G is an octal-low-side power switch which provides a serial peripheral interface (SPI) to control the 8 power DMOS switches, as well as diagnostic feedback. The power transistors are protected against short to  $V_{\rm BB}$ , overload, overtemperature and against overvoltage by an active zener clamp.

The diagnostic logic recognizes a fault condition which can be read out via the serial diagnostic output (SO).

# **Circuit Description**

### Output Stage Control

Each output is independently controlled by an output latch and a common reset line, which disables all eight outputs. Serial data input (SI) is read on the falling edge of the serial clock. A logic high input data bit turns the respective output channel ON, a logic low data bit turns it OFF.  $\overline{CS}$  must be low whilst shifting all the serial data into the device. A low-to-high transition of  $\overline{CS}$  transfers the serial data input bits to the output buffer.

#### Special conditions for Channel 1 to 4:

In addition to the serial control of the outputs it is possible to control channel 1 to channel 4 directly in parallel for PWM applications. These inputs are high active and **ORed** with the SPI control bit. The parallel inputs are provided with internal pull down sources, to guarantee that the channels are switched off when the inputs are not connected.

The table shows the OR-operation of the parallel inputs 1 ..4 and the corresponding SPI bits.

IN 1 - 4	SF	PI-Bit 0 - 3	OUT 1 - 4
0		0	OFF
0	0		ON
1		0	ON
1		1	ON
SPI-Bit 4 -	7	OUT 5 - 8	
0		OFF	
1		ON	

The outputs 5 .. 8 can be controlled in serial via SPI Interface

#### Serial Control Bits (SI)

Ch. 8	Ch. 7	Ch. 6	Ch. 5	Ch. 4	Ch. 3	Ch. 2	Ch. 1
7	6	5	4	3	2	1	0
MSB		-					I SB

#### Serial Diagnostic Bits (SO)

DIAG7	DIAG6	DIAG5	DIAG4	DIAG3	DIAG2	DIAG1	DIAG0
7	6	5	4	3	2	1	0
MSB							LSB



### Power Transistor Protection Functions<sup>1)</sup>

Each of the eight output stages has its own zener clamp, which causes a voltage limitation at the power transistor when solenoid loads are switched off. The outputs are provided with a current limitation set to a minimum of 500 mA. The continuous current for each channel is 200 mA (all channels ON).

Each output is protected by embedded protection functions. In the event of an overload or short to supply, the current is internally limited and a fault bit is generated for each output individually (early warning). If this operation leads to an overtemperature condition, a second protection level (about 170 °C) will change the output into a low duty cycle PWM (channel selective thermal shutdown with restart) to prevent critical chip temperatures.

# **SPI Signal Description**

 $\overline{CS}$  - Chip Select. The system microcontroller selects the TLE 6236 G by means of the  $\overline{CS}$  pin. Whenever the pin is in a logic low state, data can be transferred from the  $\mu$ C and vice versa.

**CS** High to Low transition: - diagnostic status information is transferred from the power

outputs into the shift register.

- serial input data can be clocked in from then on

- SO changes from high impedance state to logic high or low

state corresponding to the SO bits

**CS** Low to High transition: - transfer of SI bits from shift register into output buffers - reset of diagnosis register

To avoid any false clocking the serial clock input pin SCLK should be logic low state during high to low transition of  $\overline{CS}$ . When  $\overline{CS}$  is in a logic high state, any signals at the SCLK and SI pins are ignored and SO is forced\_into a high impedance state.

The device will react to the CS  $\_$  only if one correct SCLK $\_$  signal has been sent.

**SCLK** - Serial Clock. The system clock pin clocks the internal shift register of the TLE 6236 G. The serial input (SI) accepts data into the input shift register on the falling edge of SCLK while the serial output (SO) shifts diagnostic information out of the shift register on the rising edge of serial clock. It is essential that the SCLK pin is in a logic low state whenever chip select  $\overline{CS}$  makes any transition.

**SI** - Serial Input. Serial data bits are shifted in at this pin, the most significant bit first. SI information is read in on the falling edge of SCLK. Input data is latched in the shift register and then transferred to the control buffer of the output stages.

A logic high bit at this pin (within the data byte) will switch the corresponding output on.

<sup>&</sup>lt;sup>1)</sup>The integrated protection functions prevent an IC destruction under fault conditions and may not be used in normal operation or permanently



**SO** - Serial Output. Diagnostic data bits are shifted out serially at this pin, the most significant bit first. SO is in a high impedance state until the  $\overline{CS}$  pin goes to a logic low state. New diagnostic data will appear at the SO pin following the rising edge of SCLK.

**RESET** - Reset pin. If the reset pin is in a logic low state, it clears the SPI shift register and switches all outputs OFF. An internal pull-up structure is provided on chip.

# Diagnostics

**FAULT** - Fault pin. There is a general fault pin (open drain) which shows a high to low transition as soon as an error occurs for any one of the eight channels. This fault indication can be used to generate a  $\mu$ C interrupt. Therefore a 'diagnosis' interrupt routine need only be called after this fault indication. This saves processor time compared to a cyclic reading of the SO information.

As soon as a fault occurs, the fault information is latched into the diagnosis register. Serial data out pin (SO) is in a high impedance state when  $\overline{CS}$  is high. If  $\overline{CS}$  receives a LOW signal, all diagnosis bits can be shifted out serially. The rising edge of  $\overline{CS}$  will reset all error registers.

	Parallel Input	SI Bits 0-7	SO DIAG- Bits 0-7	Output State	Output voltage V <sub>OUT</sub>	Operating Mode
1	L	L	L	OFF	>Vref	normal function
2	L	Н	Н	ON	< Vref	normal function
3	Н	L	L	ON	< Vref	normal function
4	Н	Н	Н	ON	< Vref	normal function
5	L	L	Н	OFF	< Vref	open load/short to gnd
6	L	Н	L	ON	>Vref	overload
7	Н	L	Н	ON	>Vref	overload
8	Н	Н	L	ON	>Vref	overload

Logic table

**Table 1:** Definition of diagnostic bits under parallel and serial control

### Basic principle of fault detection:

SO Bit = SI Bit:Normal FunctionSO Bit inverse to SI Bit :Fault Condition

The diagnostic bits DIAG0 to DIAG3 for channel 1 to 4 indicate a fault when the DIAG bit is high during parallel control (IN1 .. IN4 = H; serial data bits 0 .. 3 = L). Note that the SPI serial input (SI) bit overrides the ON state control from IN1 to IN4 regarding diagnostic information. Compare DIAG Bit in line 3 (parallel ON only) with DIAG Bit in line 4 (serial and parallel ON) under normal function.

Compare DIAG Bit in line 7 (parallel ON only) with DIAG Bit in line 8 (serial and parallel ON) under fault condition.



#### SPI serial input (SI) bit overrides the parallel ON state control from IN1 to IN4

Vref is the threshold reference level for detecting an Open Load/Overload The standard way of obtaining diagnostic information is as follows:

The standard way of obtaining diagnostic information is as follows:

Clock in serial information into SI pin and wait approximately 200  $\mu$ s to allow the outputs to settle. Clock in the identical serial information once again - during this process the data coming out at SO contains the bit combinations representing the diagnosis conditions as described in figure 1.

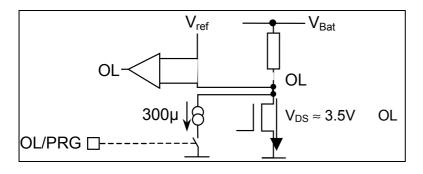
Based on the needs of the application, a software routine should be programmed into the micro controller to set the corrective action of each fault condition.

### Open Load Program Pin (OL/PRG)

To detect open load/short to ground each channel has an internal pull down source (300  $\mu$ A typ.) which pulls the drain voltage under the detection threshold in case of an open load or short to ground condition.

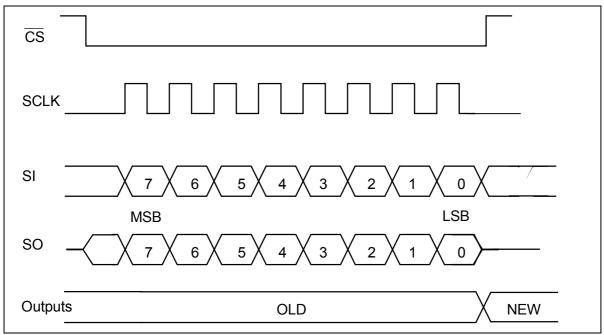
If the TLE 6236 G is used to drive LEDs this pull down current could causes a slight glowing of the LED. To avoid this, the device is provided with a program pin, which enables or disables this open load detection. The OL/PRG pin is internally pulled up, i.e. the open load detection is enabled if the OL/PRG pin is not connected. To disable the open load detection this pin must be pulled to GND, e.g with a micro controller port.

In this way the open load detection can be enabled (e.g during start up of the system or in a diagnosis routine) and disabled (e.g. during normal operation to avoid LED glowing) by the  $\mu$ C. If the open load detection is disabled, the leakage current is reduced to a maximum of  $1\mu$ A.

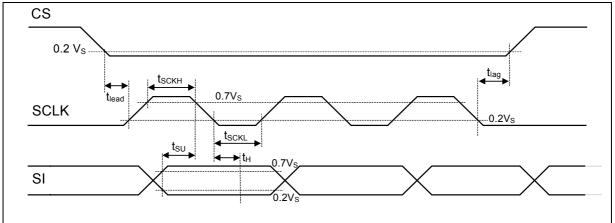




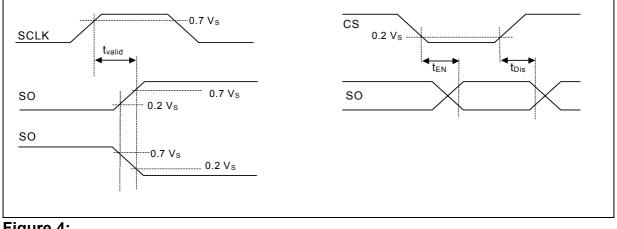
**Timing Diagrams** 



# Figure 2: Serial Interface



### Figure 3: Input Timing Diagram

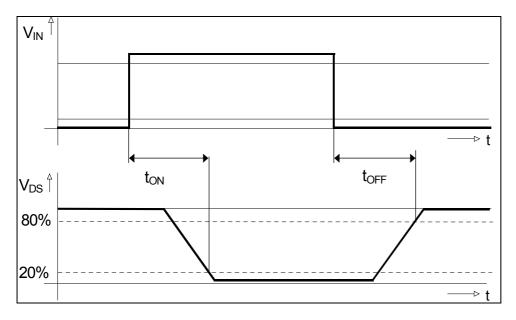


#### Figure 4: SO Valid Time Waveforms

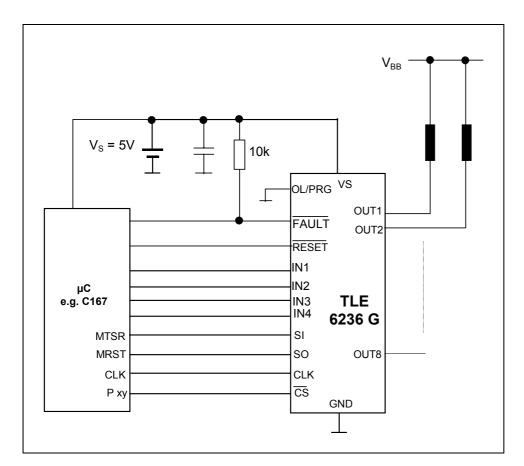
Enable and Disable Time Waveforms



# **Application Circuits**



### Figure 5: Power Outputs





# **Typical electrical Characteristics**

### **Drain-Source on-resistance**

 $R_{DS(ON)} = f(T_j); V_s = 5V$ 

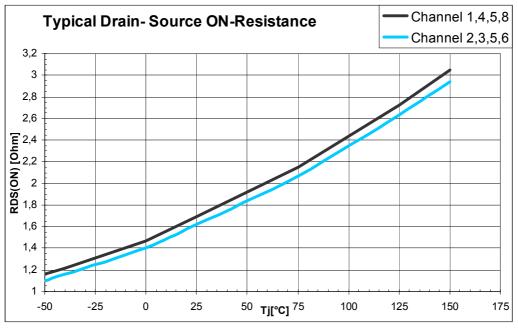
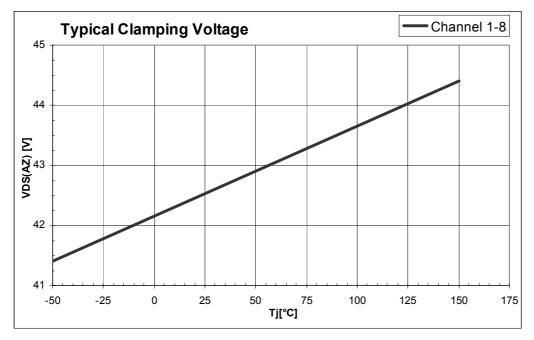


Figure 6 : Typical ON Resistance versus Junction-Temperature Channel 1-8

# **Output Clamping Voltage**

 $V_{DS(AZ)} = f(T_j); V_s = 5V$ 



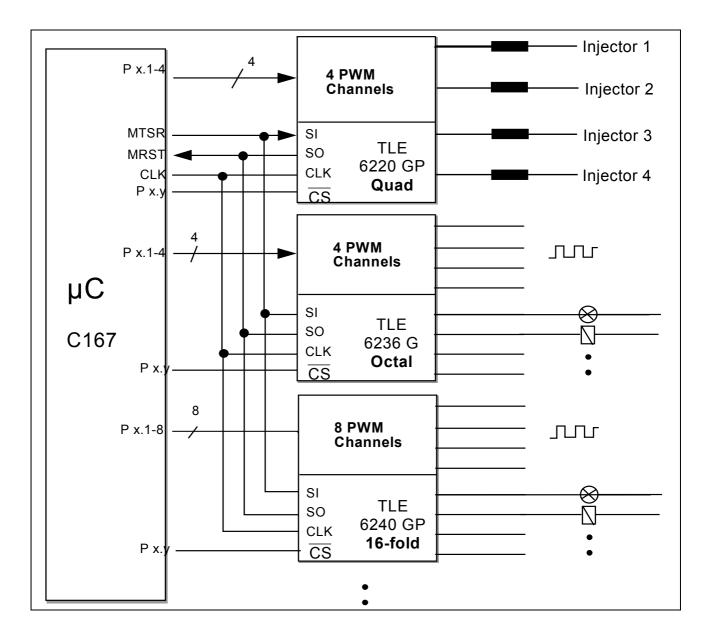
# **Figure 7 :** Typical Clamp Voltage versus Junction-Temperature Channel 1-8



# **Parallel SPI Configuration**

#### **Engine Management Application**

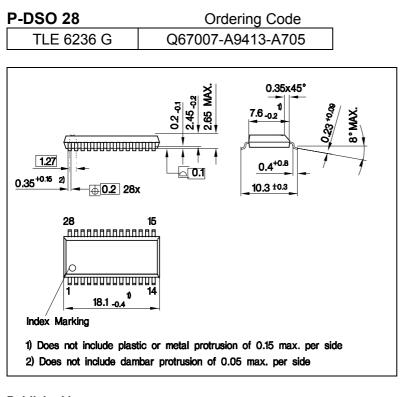
TLE 6236 G in combination with TLE 6240 GP (16-fold switch) for relays and general purpose loads and TLE 6220 GP (quad switch) to drive the injector valves. This arrangement covers the numerous loads to be driven in a modern Engine Management/Powertrain system. From 28 channels in sum 16 can be controlled direct in parallel for PWM applications.





# Package and Ordering Code

#### (all dimensions in mm)



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